DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC143Z series NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Product specification Supersedes data of 2004 Apr 06 2004 Aug 16





PDTC143Z series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	4.7	_	kΩ
R2	bias resistor	47	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACE	KAGE	MARKING CODE	DND COMPLEMENT
I TPE NUMBER	PHILIPS	EIAJ	MARKING CODE	PNP COMPLEMENT
PDTC143ZE	SOT416	SC-75	38	PDTA143ZE
PDTC143ZEF	SOT490	SC-89	53	PDTA143ZEF
PDTC143ZK	SOT346	SC-59	18	PDTA143ZK
PDTC143ZM	SOT883	SC-101	E3	PDTA143ZM
PDTC143ZS	SOT54 (TO-92)	SC-43	TC143Z	PDTA143ZS
PDTC143ZT	SOT23	_	*18 ⁽¹⁾	PDTA143ZT
PDTC143ZU	SOT323	SC-70	*54 ⁽¹⁾	PDTA143ZU

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Note

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^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC143ZS	1 R1 R2	1 2 3	base collector emitter
PDTC143ZE PDTC143ZEF PDTC143ZK PDTC143ZT PDTC143ZU	Top view Top view Top view Top view	1 2 3	base emitter collector
PDTC143ZM	2 R1 R2 R2 Dottom view MHC506	1 2 3	base emitter collector

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PDTC143Z series

ORDERING INFORMATION

TYPE NUMBER		PACKAGE	
NAME		DESCRIPTION	VERSION
PDTC143ZE	_	plastic surface mounted package; 3 leads	SOT416
PDTC143ZEF	-	plastic surface mounted package; 3 leads	SOT490
PDTC143ZK	-	plastic surface mounted package; 3 leads	SOT346
PDTC143ZM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm	SOT883
PDTC143ZS	-	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTC143ZT	_	plastic surface mounted package; 3 leads	SOT23
PDTC143ZU	_	plastic surface mounted package; 3 leads	SOT323

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V _{EBO}	emitter-base voltage	open collector	_	10	V
VI	input voltage				
	positive		_	+30	V
	negative		_	- 5	V
I _O	output current (DC)		_	100	mA
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

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PDTC143Z series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	_	_	170	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	100	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$	_	_	100	mV
$V_{i(off)}$	input-off voltage	$I_C = 100 \mu\text{A}; V_{CE} = 5 \text{V}$	_	0.6	0.5	V
$V_{i(on)}$	input-on voltage	$I_C = 5 \text{ mA}; V_{CE} = 0.3 \text{ V}$	1.3	0.9	_	٧
R1	input resistor		3.3	4.7	6.1	kΩ
R2 R1	resistor ratio		8	10	12	
C _c	collector capacitance	$I_E = I_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	_	_	2.5	pF

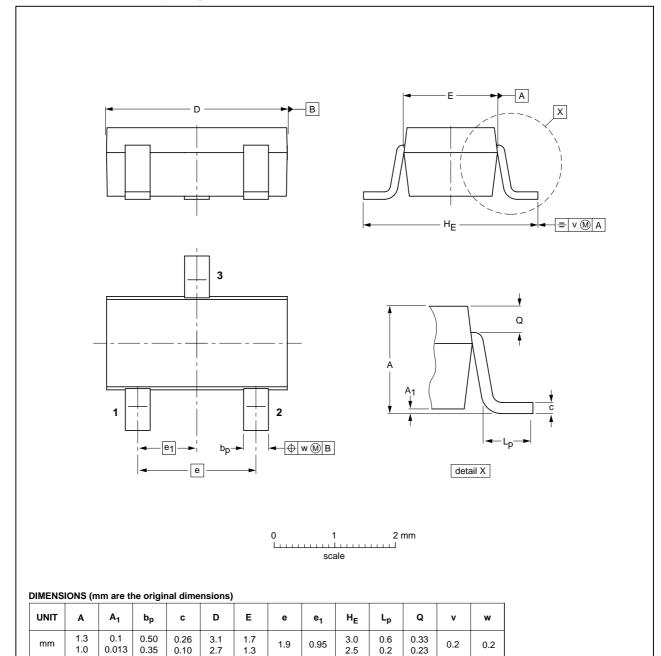
NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

PACKAGE OUTLINES

Plastic surface mounted package; 3 leads

SOT346

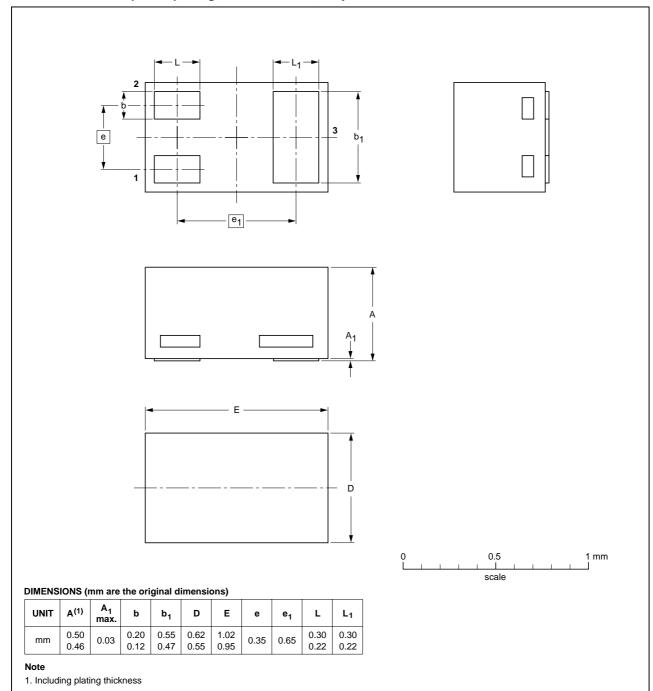


OUTLINE		REFERENCES EUROPEAN		ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59		98-07-17	

PDTC143Z series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



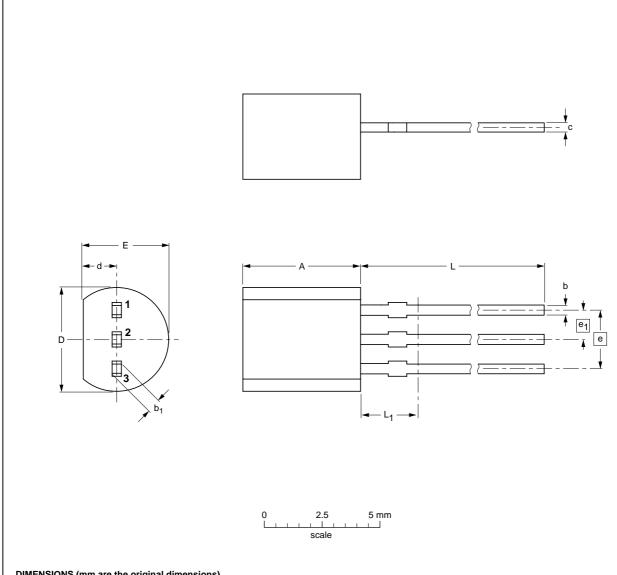
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VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT883			SC-101		03-02-05 03-04-03	

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

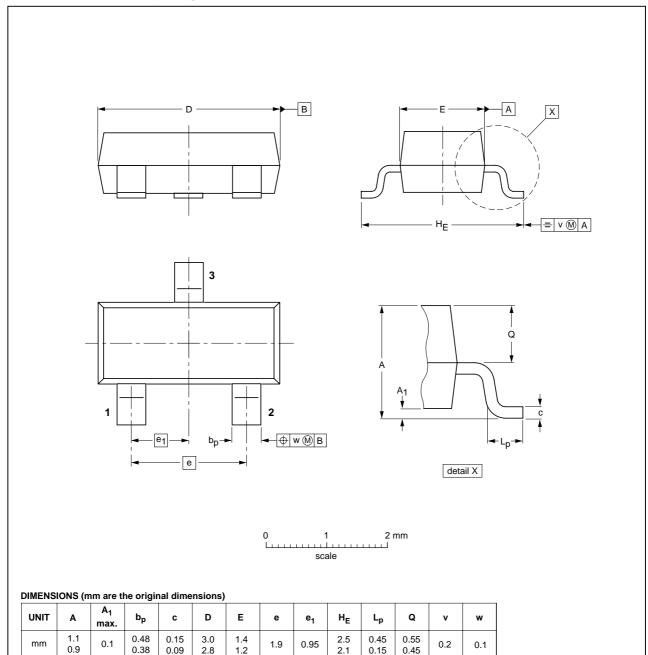
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VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43A			97-02-28 04-06-28	

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PDTC143Z series

Plastic surface mounted package; 3 leads

SOT23

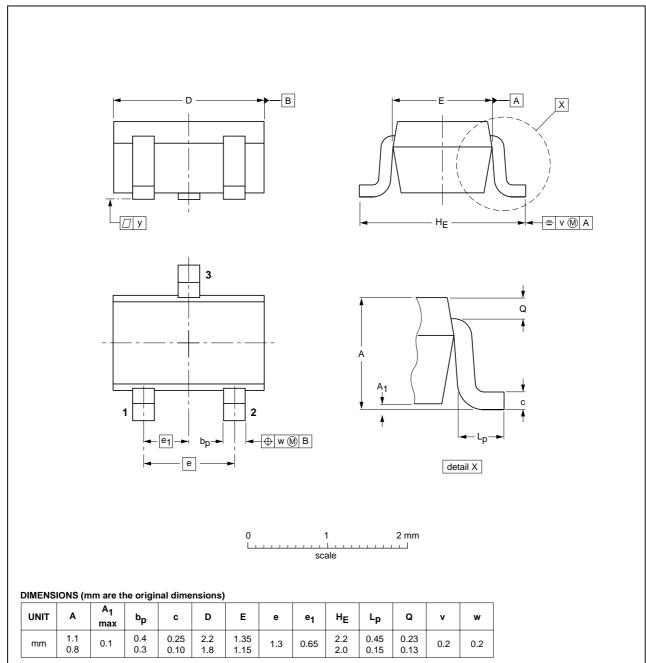


	REFER	ENCES	EUROPEAN	ISSUE DATE
IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
	TO-236AB			97-02-28 99-09-13
	IEC	IEC JEDEC	IEC JEDEC EIAJ	IEC JEDEC EIAJ PROJECTION

PDTC143Z series

Plastic surface mounted package; 3 leads

SOT323

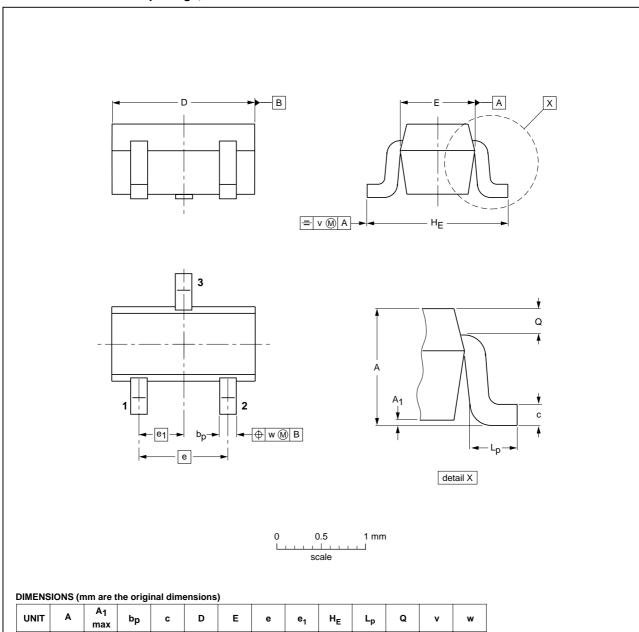


	OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
		IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
	SOT323			SC-70			97-02-28

PDTC143Z series

Plastic surface mounted package; 3 leads

SOT416



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
SOT416			SC-75			97-02-28

1.75

1

0.5

0.45

0.23

0.2

0.2

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0.30

0.95

0.1

0.25

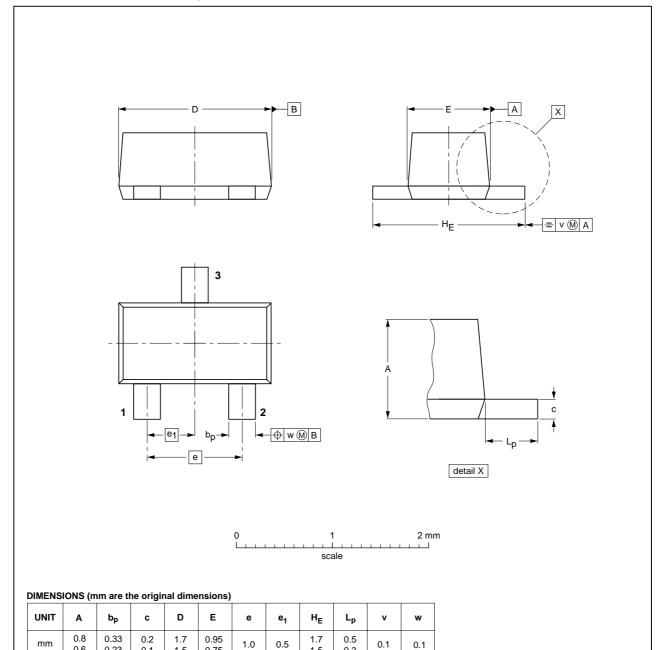
0.10

1.8

PDTC143Z series

Plastic surface mounted package; 3 leads

SOT490



OUTLINE	REFERENCES			EUROPEAN	IOOUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT490			SC-89			98-10-23

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0.6

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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